# **VHF/UHF Transistor**

## **NPN Silicon**

## **Features**

• Pb-Free Package is Available

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	15	Vdc
Collector - Base Voltage	$V_{CBO}$	30	Vdc
Emitter-Base Voltage	$V_{EBO}$	3.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	50	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C	P <sub>D</sub>	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C	$P_{D}$	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

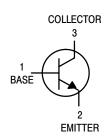
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

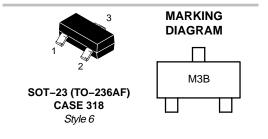
- 1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



## ON Semiconductor®

## http://onsemi.com





МЗВ = Specific Device Code

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMBT918LT1	SOT-23	3000 / Tape & Reel
MMBT918LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			-	
Collector – Emitter Breakdown Voltage ( $I_C = 3.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)</sub> CEO	15	-	Vdc
Collector – Base Breakdown Voltage ( $I_C = 1.0 \mu Adc, I_E = 0$ )	V <sub>(BR)</sub> CBO	30	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu Adc$ , $I_C = 0$ )	V <sub>(BR)EBO</sub>	3.0	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 15 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	50	nAdc
ON CHARACTERISTICS			•	
DC Current Gain ( $I_C = 3.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$ )	h <sub>FE</sub>	20	-	_
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc)	V <sub>CE(sat)</sub>	_	0.4	Vdc
Base – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ )	V <sub>BE(sat)</sub>	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS			-	
Current – Gain – Bandwidth Product (I <sub>C</sub> = 4.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	f <sub>T</sub>	600	_	MHz
Output Capacitance $(V_{CB} = 0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$ $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>obo</sub>	<u>-</u>	3.0 1.7	pF
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	_	2.0	pF
Noise Figure (I <sub>C</sub> = 1.0 mAdc, $V_{CE}$ = 6.0 Vdc, $R_{S}$ = 50 $\Omega$ , f = 60 MHz) (Figure 1)	NF	-	6.0	dB
Power Output ( $I_C = 8.0 \text{ mAdc}$ , $V_{CB} = 15 \text{ Vdc}$ , $f = 500 \text{ MHz}$ )	P <sub>out</sub>	30	-	mW
Common–Emitter Amplifier Power Gain (I <sub>C</sub> = 6.0 mAdc, V <sub>CB</sub> = 12 Vdc, f = 200 MHz)	G <sub>pe</sub>	11	_	dB

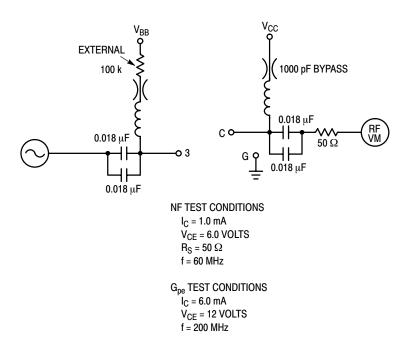
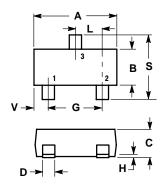


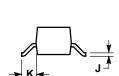
Figure 1. NF,  $G_{pe}$  Measurement Circuit 20–200

#### PACKAGE DIMENSIONS

## SOT-23 (TO-236)

CASE 318-08 **ISSUE AH** 





#### NOTES:

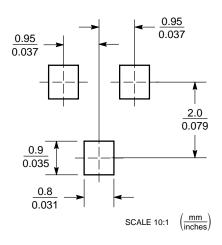
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
   MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE
- 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

	INCHES		MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
Н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
v	0.0177	0.0236	0.45	0.60

#### STYLE 6:

- PIN 1. BASE
  - **EMITTER**
  - COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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